

TYN40B-800T

Rev.01 - 18 October 2023

Product data sheet

1. General description

Planar passivated Silicon Controlled Rectifier (SCR) in a TO263 plastic package intended for use in applications requiring very high inrush current capability, high thermal cycling performance and high junction temperature capability ($T_{i(max)} = 150$ °C).

2. Features and benefits

- High junction operating temperature capability (T_{j(max)} = 150 °C)
- Very high current surge capability
- · Planar passivated for voltage ruggedness and reliability
- High turn-on current rise $dI_T/dt = 150 A/\mu s$
- High noise immunity dV_D/dt = 500 V/µs up to 150 °C
- High thermal cycling performance
- High voltage capability

3. Applications

- High voltage capability
- Protection circuits e.g. SMPS inrush current
- Motor control circuits and starters
- · Voltage regulation
- Solid state relays

4. Quick reference data

Symbol	Parameter	Conditions	Notes		Values		Unit
V _{DRM}	repetitive peak off-state voltage				800		V
$I_{T(RMS)}$	RMS on-state current	half sine wave; T _{mb} ≤ 136 °C; <u>Fig. 1; Fig. 2; Fig. 3</u>			40		A
I _{TSM}	non-repetitive peak on- state current	half sine wave; T _{j(init)} = 25 °C; t _p = 10 ms; <u>Fig. 4; Fig. 5</u>			450		A
		half sine wave; $T_{j(init)}$ = 25 °C; t_p = 8.3 ms			495		А
T _j	junction temperature			-40 to 150		°C	
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static cha	racteristics						
I _{GT}	gate trigger current	V_{D} = 12 V; I_{T} = 0.1 A; T_{j} = 25 °C; Fig. 7		-	-	15	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>		-	-	60	mA
V _T	on-state voltage	I _T = 100 A; T _j = 25 °C; <u>Fig. 10</u>		-	-	1.65	V
Dynamic	characteristics						
dV_D/dt	rate of rise of off-state voltage	V_{DM} = 536 V; T _j = 150 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit		500	-	-	V/µs

5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode		
2	А	anode		А Д К G
3	G	gate		sym037
mb	A	mounting base; connected to anode	1 TO-263 (D2PAK)	

6. Ordering information

Table 3.	Ordering	information
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Type number	Package Name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
TYN40B-800T	TO263	TYN40B-800TJ	Reel	800	TO263N	28-Sep-2016

7. Marking

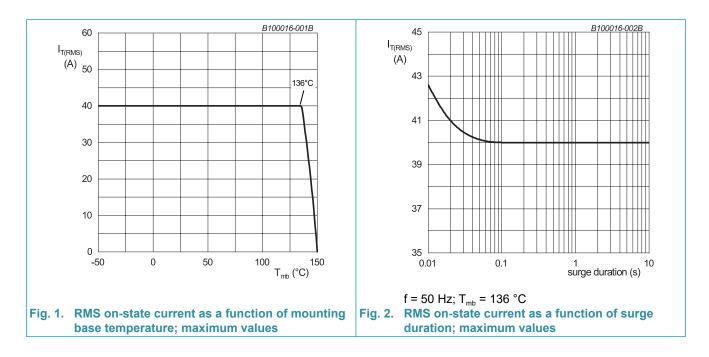
Table 4. Marking codes	
Type number	Marking codes
TYN40B-800T	TYN40B
	800T

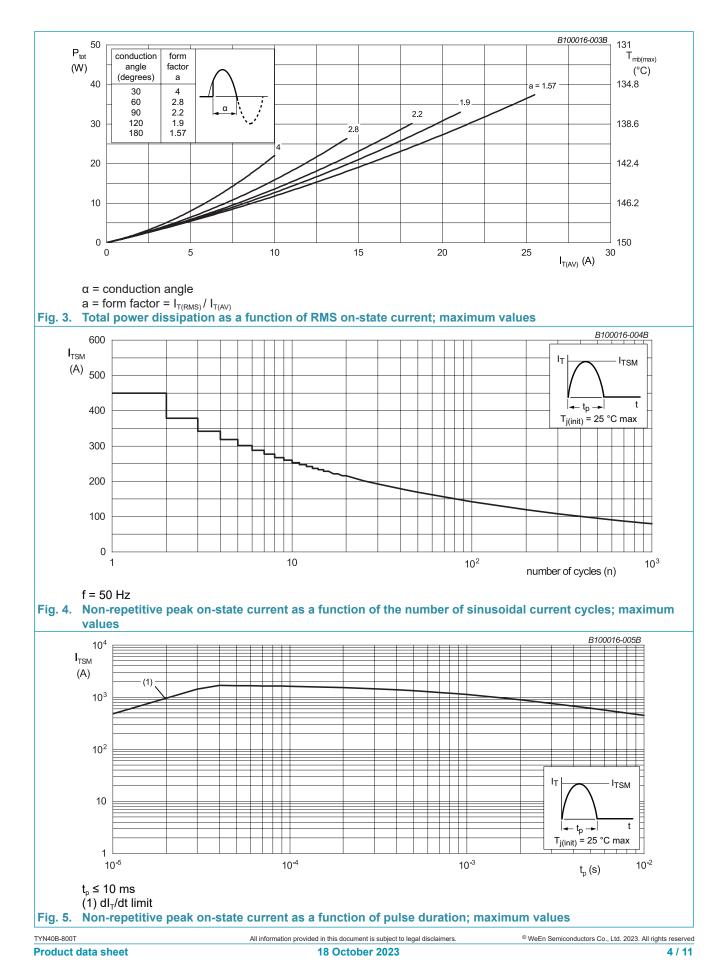
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

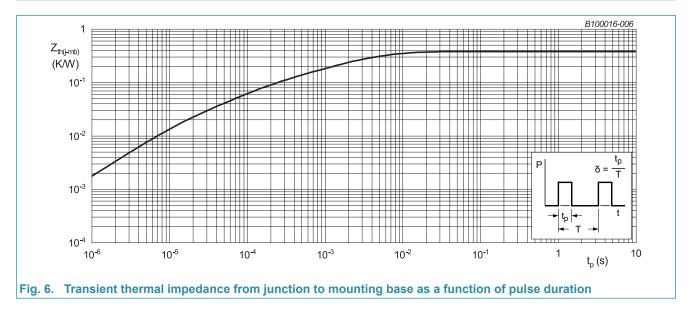
Symbol	Parameter	Conditions	Notes	Values	Unit
V_{DRM}	repetitive peak off-state voltage			800	V
V_{RRM}	repetitive peak reverse voltage			800	V
I _{T(AV)}	average on-state current	half sine wave; T _{mb} ≤ 136 °C;		25	А
I _{T(RMS)}	RMS on-state current	half sine wave; T _{mb} ≤ 136 °C; <u>Fig. 1; Fig. 2; Fig. 3</u>		40	A
I _{TSM}	non-repetitive peak on- state current	half sine wave; T _{j(init)} = 25 °C; t _p = 10 ms; <u>Fig. 4; Fig. 5</u>		450	A
		half sine wave; $T_{j(init)}$ = 25 °C; t_p = 8.3 ms		495	А
l ² t	l ² t for fusing	t _p = 10 ms; sine-wave pulse		1012	A ² s
dl _T /dt	rate of rise of on-state current	I _G = 30 mA		150	A/µs
I _{GM}	peak gate current			5	A
V_{GM}	peak gate voltage			5	V
V_{GRM}	peak reverse gate voltage			7	V
P _{GM}	peak gate power			20	W
$P_{G(AV)}$	average gate power	over any 20 ms period		1	W
T _{stg}	storage temperature			-40 to 150	°C
T _i	junction temperature			-40 to 150	°C





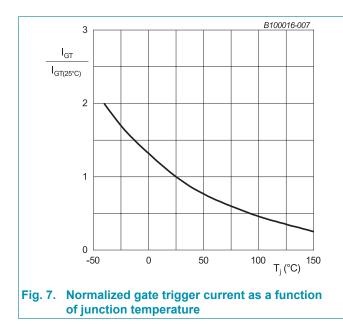
9. Thermal characteristics

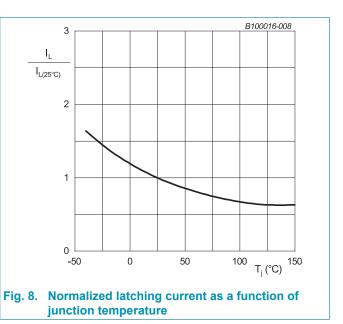
Table 6. Th	ermal characteristics						
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	<u>Fig. 6</u>		-	-	0.38	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air		-	60	-	K/W

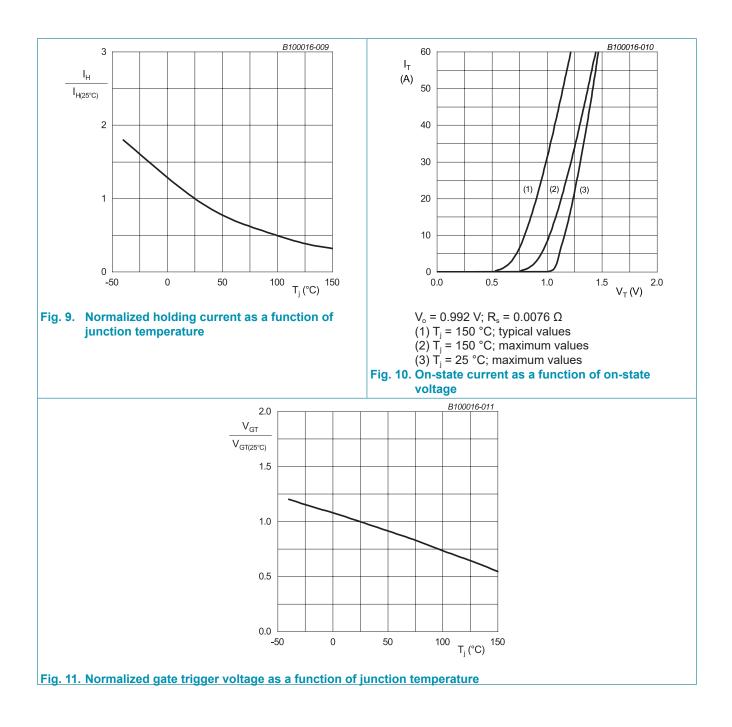


10. Characteristics

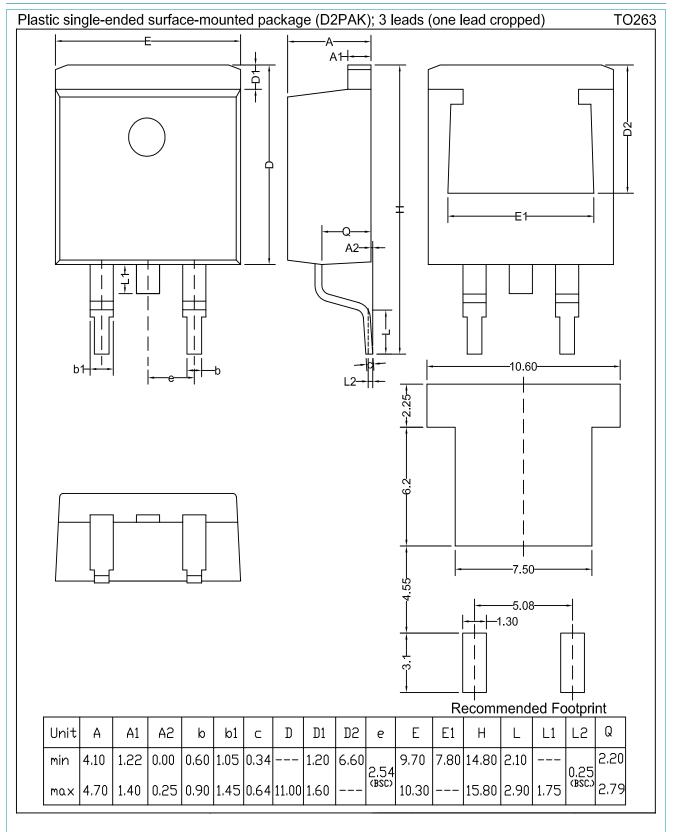
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
	racteristics						
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 7</u>		-	-	15	mA
I _L	latching current	$V_{\rm D}$ = 12 V; I _G = 0.1 A; T _j = 25 °C; <u>Fig. 8</u>		-	-	80	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>		-	-	60	mA
V _T	on-state voltage	I _T = 100 A; T _j = 25 °C; <u>Fig. 10</u>		-	-	1.65	V
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 11</u>		-	0.7	1.2	V
		V _D = 400 V; I _T = 0.1 A; T _j = 150 °C		0.25	0.5	-	V
I _D	off-state current	V _D = 800 V; T _j = 25 °C		-	-	5	μA
		V _D = 800 V; T _j = 150 °C		-	-	2	mA
I _R	reverse current	V _D = 800 V; T _j = 25 °C		-	-	5	μA
		V _D = 800 V; T _j = 150 °C		-	-	2	mA
Dynamic	characteristics	·					
dV _D /dt	rate of rise of off-state voltage	$V_{DM} = 536 \text{ V}; \text{ T}_{\text{j}} = 150 \text{ °C}; (V_{DM} = 67\% \text{ of } V_{DRM}); exponential waveform; gate open circuit$		500	-	-	V/µs
t _{gt}	gate-controlled turn-on time	I_{TM} = 50 A; V _D = 800 V; I _G = 30 mA; dI _G /dt = 5 A/µs; T _j = 25 °C		-	2	-	μs
t _q	commutated turn-off time	I_{TM} = 2 A; t _p = 50 µs; dV/dt = 5 V/µs; dI/dt = 30 A/µs; T _i = 25 °C		-	-	25	μs







11. Package outline



12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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